## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Euijoon Yoon ea al.

Examiner: MALDONADO, JULIO J

Serial No.:

10/563,854

Group Art Unit: 2823

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For: GROWTH METHOD FOR NITRIDE:

SEMICONDUCTOR EPITAXIAL LAYERS:

Customer No.: 27128

Confirmation No.: 3828

Last Office Action:

June 9, 2010

## **AMENDMENT AFTER RCE**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Office Action mailed June 9, 2010, please amend the above-identified application in accordance with the amendments and remarks as set forth herein.

**Amendments to the Claims** are reflected in the listing of claims which begin on page 2 of this document.

Remarks/Arguments begin on page 6 of this document.